

DATA SHEET

SMP1307 Series: Very Low Distortion Attenuator Plastic Packaged PIN Diodes

Features

- Low-distortion design
- Frequency range from HF to > 2 GHz
- Designed for CATV AGC applications
- Designed for high-volume wireless applications
- Available lead (Pb)-free and RoHS-compliant MSL-1 @ 260 °C⁽¹⁾ per JEDEC J-STD-020


Description

The SMP1307 series of plastic packaged, surface mountable, low capacitance (0.3 pF) silicon PIN diodes is designed for use in attenuator applications from 5 MHz to beyond 2 GHz. The thick 175 μm I region of these PIN diodes makes them very attractive for use in very low distortion PI and TEE attenuators commonly used in TV distribution applications. The 1.5 μs typical carrier life-time of these diodes results in resistance of 100 Ω maximum at 1 mA and 10 Ω maximum at 10 mA. Available in a selection of plastic packages, as a single diode in the small footprint SOD-323, and in a variety of configurations in the SOT-23. Also available in a SOT-5 (SMP1307-027) package as a four-diode array designed for insertion in the commonly used four-diode PI attenuator circuit.

NEW

Skyworks offers lead (Pb)-free, RoHS (Restriction of Hazardous Substances)-compliant packaging.








Absolute Maximum Ratings


Characteristic	Value
Reverse voltage (V_R)	200 V
Power dissipation @ 25 °C lead temperature (P_D)	250 mW
Storage temperature (T_{ST})	-65 °C to +150 °C
Operating temperature (T_{OP})	-65 °C to +150 °C
ESD human body model	Class 1C


Performance is guaranteed only under the conditions listed in the specifications table and is not guaranteed under the full range(s) described by the Absolute Maximum specifications. Exceeding any of the absolute maximum/minimum specifications may result in permanent damage to the device and will void the warranty.

CAUTION: Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions must be employed at all times.

1. SOT-5 (-027) MSL to be defined.

					
Single	Common Anode	Common Cathode	Series Pair	Single	PI
SOT-23	SOT-23	SOT-23	SOT-23	SOD-323	SOT-5
◆SMP1307-001 Marking: PJ1		SMP1307-004 Marking: PJ3	SMP1307-005 Marking: PJ2	SMP1307-011 Marking: PJ	SMP1307-027 Marking: PJM
◆SMP1307-001LF Marking: RJ1	SMP1307-003LF Marking: RJ9	SMP1307-004LF Marking: RJ3	SMP1307-005LF Marking: RJ2	SMP1307-011LF Marking: RJ	SMP1307-027LF Marking: RJM
$L_S = 1.5 \text{ nH}$	$L_S = 1.5 \text{ nH}$	$L_S = 1.5 \text{ nH}$	$L_S = 1.5 \text{ nH}$	$L_S = 1.5 \text{ nH}$	

 LF denotes lead (Pb)-free, RoHS-compliant packaging option as an alternative to our standard tin/lead (Sn/Pb) packaging.

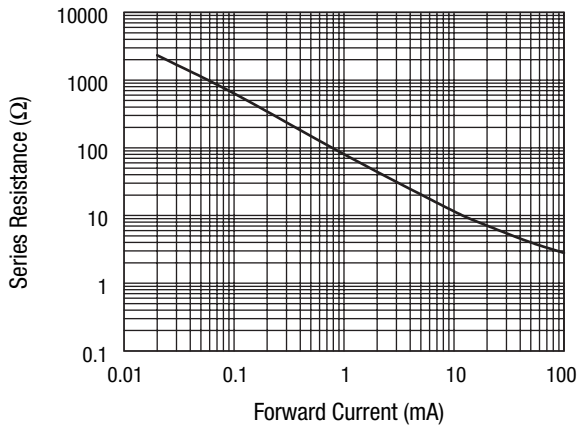
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Electrical Specifications at 25 °C

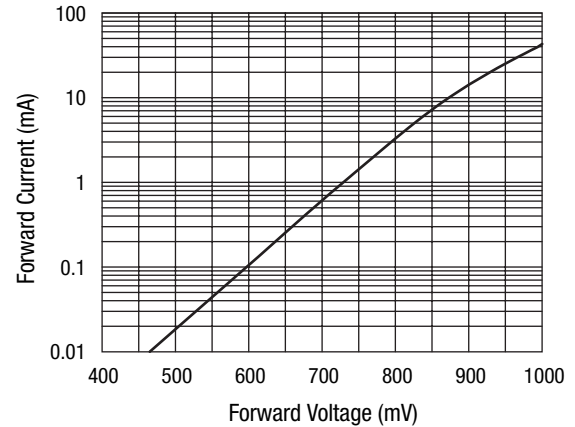
Parameter	Condition	Typ.	Max.	Unit
Reverse current (I_R)	$V_R = 200 \text{ V}$		10	μA
Capacitance (C_T) ⁽¹⁾	$F = 1 \text{ MHz}, V = 30 \text{ V}$		0.3	pF
Resistance (R_S)	$F = 100 \text{ MHz}, I = 1 \text{ mA}$	75	100	Ω
Resistance (R_S)	$F = 100 \text{ MHz}, I = 10 \text{ mA}$		15	Ω
Resistance (R_S)	$F = 100 \text{ MHz}, I = 100 \text{ mA}$		3	Ω
Forward voltage (V_F)	$I_F = 10 \text{ mA}$	0.85		V
Carrier lifetime (TI)	$I_F = 10 \text{ mA}$	1.5		μs
I region width		175		μm

1. The SMP1307-027 maximum capacitance is 0.45 pF.

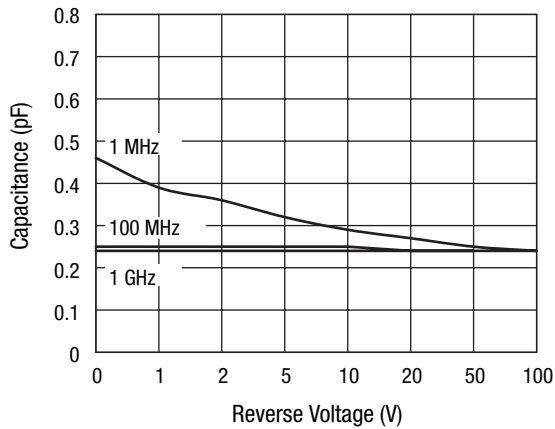
Typical Performance Data



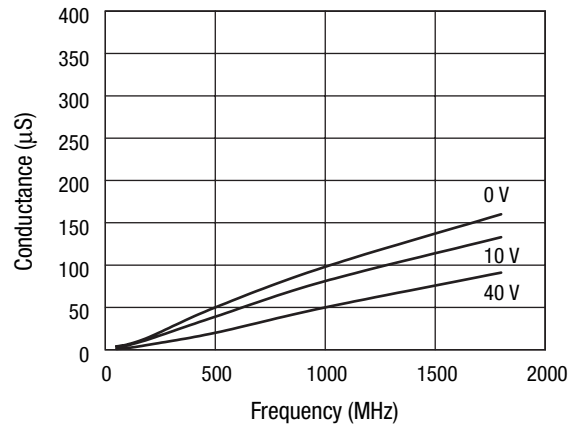
Series Resistance vs. Current @ 100 MHz



DC Characteristic



Capacitance vs. Reverse Voltage



Conductance vs. Frequency and Reverse Voltage

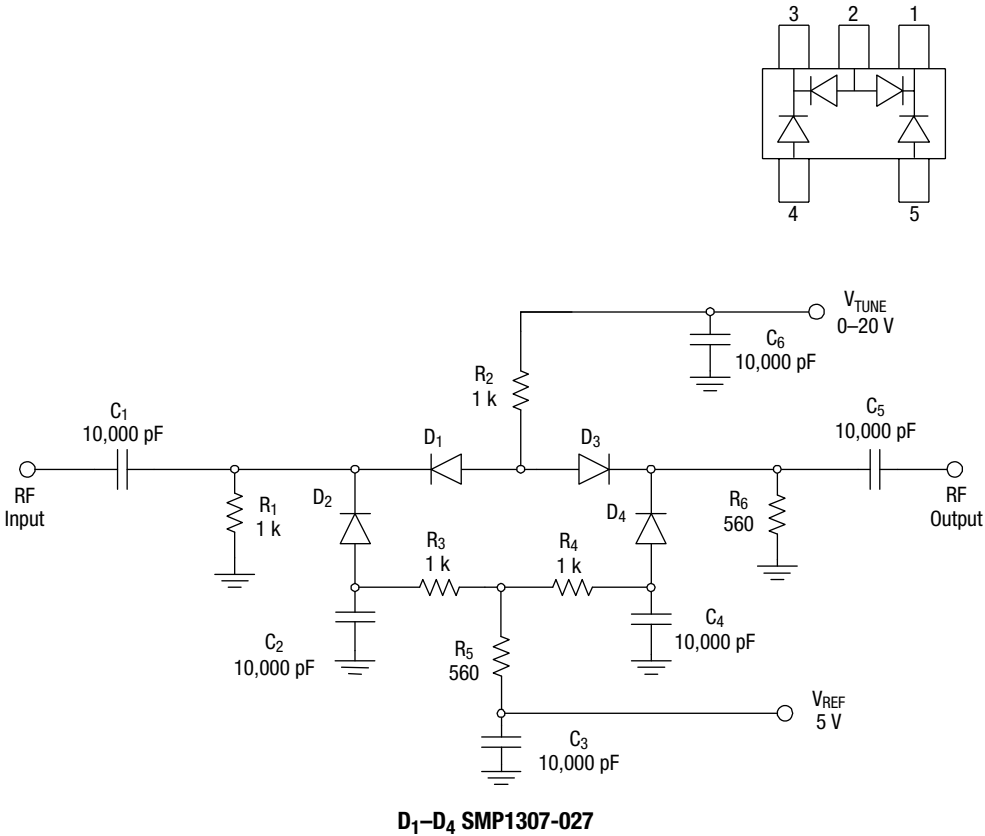
Typical Resistance vs. Temperature @ 100 MHz

I_F (mA)	R -55 °C (Ω)	R -15 °C (Ω)	R 25 °C (Ω)	R 65 °C (Ω)	R 100 °C (Ω)
0.02	2386	2360	2546	2520	2440
0.1	560	598	632	633	639
0.3	203	219	236	239	242
1	66.1	71.2	79.3	83.6	85.4
10	9.1	10	10.9	12.2	12.9
20	5.6	6	6.6	7.4	7.8
100	2.2	2.4	2.6	3	3.2

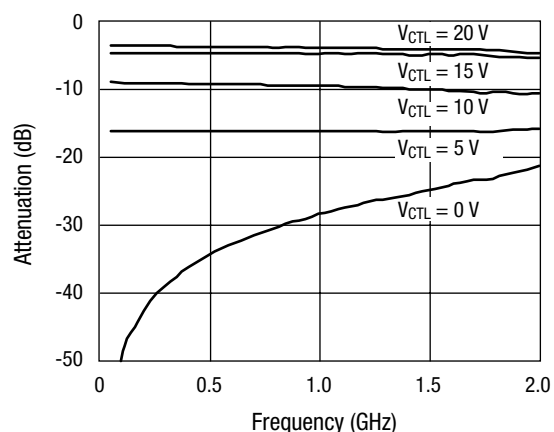
SMP1307-027 Four-Diode PI Attenuator

The SMP1307-027 employs four PIN diode junctions in a 5-lead SOT package. It is configured for ease of insertion in the PI attenuator circuit commonly used for broadband TV distribution systems, covering a frequency range from 5 MHz to beyond 1 GHz.

A broadband attenuator was designed using the SMP1307-027 showing good performance to 2 GHz. The attenuator was evaluated with a 50 Ω source and load impedance. The following figure shows the circuit diagram and measured performance.



A 4-diode PI attenuator utilizing individual SMP1307-011 PIN diodes is described in the "A Wideband General Purpose PIN Diode Attenuator" Application Note.



SMP1307-027 Attenuation vs. Frequency

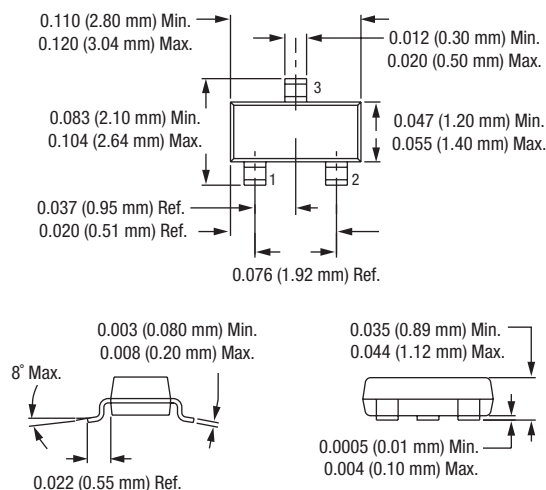
Recommended Solder Reflow Profiles

Refer to the *“Recommended Solder Reflow Profile”* Application Note.

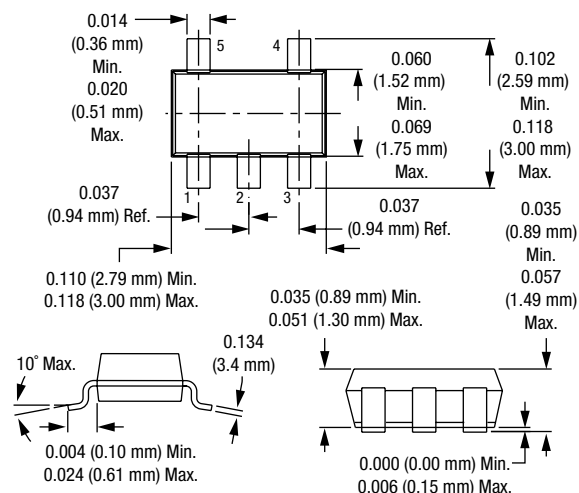
Tape and Reel Information

Refer to the *“Discrete Devices and IC Switch/Attenuators Tape and Reel Package Orientation”* Application Note.

SOT-23



SOT-5



SOD-323

